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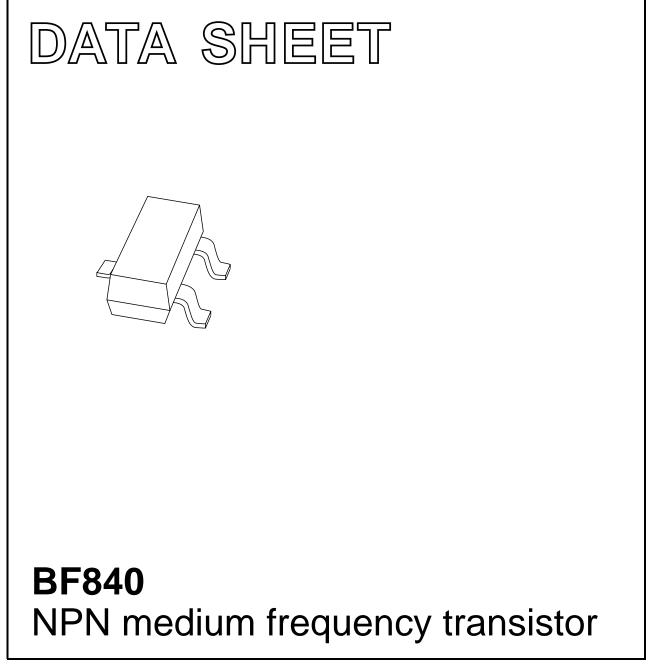
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Kind regards,

Team Nexperia

DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1999 Apr 12 2004 Jan 13



FEATURES

- Low current (max. 25 mA)
- Low voltage (max. 40 V).

APPLICATIONS

- AM mixers
- IF amplifiers in AM/FM receivers.

DESCRIPTION

NPN medium frequency transistor in a SOT23 plastic package.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾		
BF840	NC*		

Note

- 1. * = p : Made in Hong Kong.
 - * = t : Made in Malaysia.

* = W : Made in China.

ORDERING INFORMATION

TYPE	PACKAGE				
NUMBER	NAME	DESCRIPTION VERSION			
BF840	_	plastic surface mounted package; 3 leads	SOT23		

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

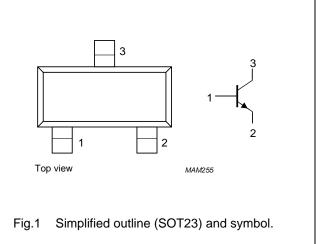
SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	40	V
V _{CEO}	collector-emitter voltage	open base	—	40	V
V _{EBO}	emitter-base voltage	open collector	-	4	V
I _C	collector current (DC)		_	25	mA
I _{CM}	peak collector current		—	25	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$; note 1	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



BF840

BF840

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W	

Note

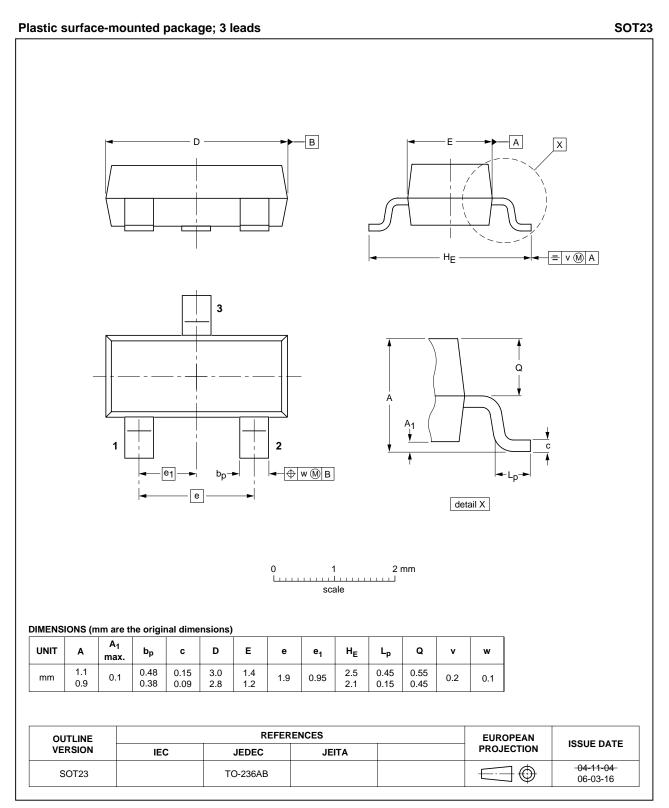
1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 20 V	-	-	100	nA
I _{EBO}	emitter cut-off current	$I_{C} = 0; V_{EB} = 4 V$	-	-	100	nA
h _{FE}	DC current gain	I _C = 1 mA; V _{CE} = 10 V	67	-	222	
V _{BE}	base-emitter voltage	I _C = 1 mA; V _{CE} = 10 V	675	725	775	mV
C _{re}	feedback capacitance	I _C = 0; V _{CB} = 10 V; f = 1 MHz	-	0.3	-	pF
f _T	transition frequency	$I_{C} = 1 \text{ mA}; V_{CE} = 10 \text{ V}; \text{ f} = 100 \text{ MHz}$	-	380	-	MHz

PACKAGE OUTLINE



BF840

BF840

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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